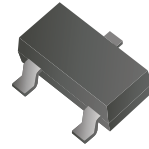


# BSS138-G

N-Channel 50-V(D-S) MOSFET  
RoHS Device



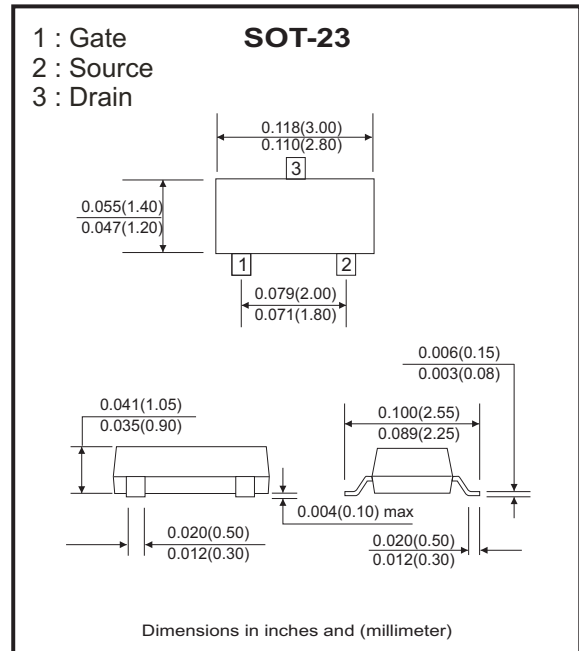
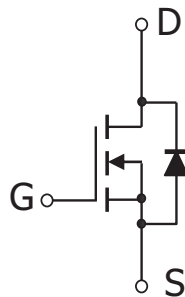
## Features

- High density cell design for extremely low  $R_{DS(ON)}$ .
- Rugged and Reliable.

## Mechanical data

- Case: SOT-23, molded plastic.
- Terminals: solderable per MIL-STD-750, method 2026.

## Circuit diagram



## Maximum Ratings (at Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Units
Drain-source voltage	V <sub>DS</sub>	50	V
Continuous gate-source voltage	V <sub>GS</sub>	±20	V
Continuous drain current	I <sub>D</sub>	0.22	A
Power dissipation	P <sub>D</sub>	0.35	W
Thermal resistance from Junction to ambient	R <sub>θJA</sub>	357	°C/W
Operating temperature	T <sub>J</sub>	150	°C
Storage temperature	T <sub>STG</sub>	-55 to +150	°C

Company reserves the right to improve product design , functions and reliability without notice.

## Electrical Characteristics (TA=25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
<b>Off characteristics</b>						
Drain-Source breakdown voltage	$V_{GS}=0V, I_D=250\mu A$	$V_{(BR)DSS}$	50			V
Gate-body leakage	$V_{DS}=0V, V_{GS}=\pm 20V$	$I_{GSS}$			$\pm 100$	nA
Zero gate voltage drain current	$V_{DS}=50V, V_{GS}=0V$	$I_{DSS}$			0.5	$\mu A$
	$V_{DS}=30V, V_{GS}=0V$	$I_{DSS}$			100	nA
<b>On characteristics</b>						
Gate-threshold voltage (note 1)	$V_{DS}=V_{GS}, I_D=1mA$	$V_{GS(th)}$	0.8		1.5	V
Static drain-source on-resistance (note 1)	$V_{GS}=10V, I_D=0.22A$	$R_{DS(ON)}$			3.5	$\Omega$
	$V_{GS}=4.5V, I_D=0.22A$				6	
Forward transconductance (note 1)	$V_{DS}=10V, I_D=0.22A$	$g_{FS}$	0.12			S
<b>Dynamic characteristics (note 2)</b>						
Input capacitance	$V_{DS}=25V, V_{GS}=0V, f=1MHz$	$C_{iss}$		27		pF
Output capacitance		$C_{oss}$		13		
Reverse transfer capacitance		$C_{rss}$		6		
<b>Switching Characteristics</b>						
Turn-on delay time (note 1,2)	$V_{DD}=30V, V_{DS}=10V, I_D=0.29A, R_{GEN}=6\Omega$	$t_{d(on)}$			5	ns
Rise time (note 1,2)		$t_r$			18	
Turn-off delay time (note 1,2)		$t_{d(off)}$			36	
Fall time (note 1,2)		$t_f$			14	
<b>Drain-source body diode characteristics</b>						
Body diode forward voltage (note 1)	$I_S=0.44A, V_{GS}=0V$	$V_{SD}$			1.4	V

Note:

1. Pulse test ; Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
2. These parameters have no way to verify.

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## RATING AND CHARACTERISTIC CURVES (BSS138-G)

Fig.1 - Output Characteristics

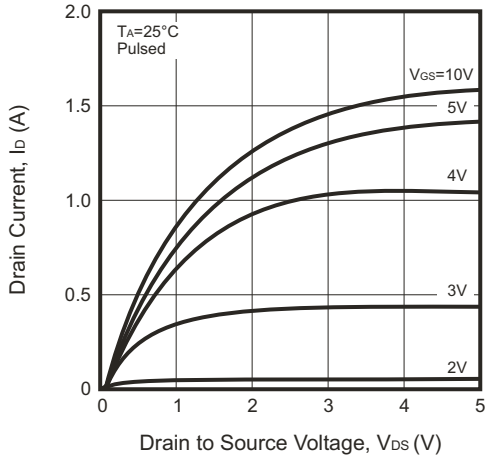


Fig.2 - Transfer Characteristics

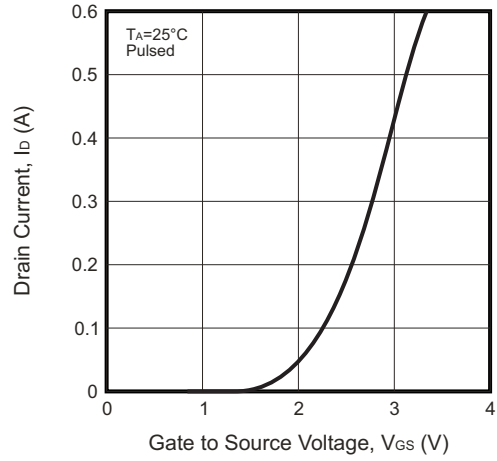


Fig.3 -  $R_{DS(ON)} - I_D$

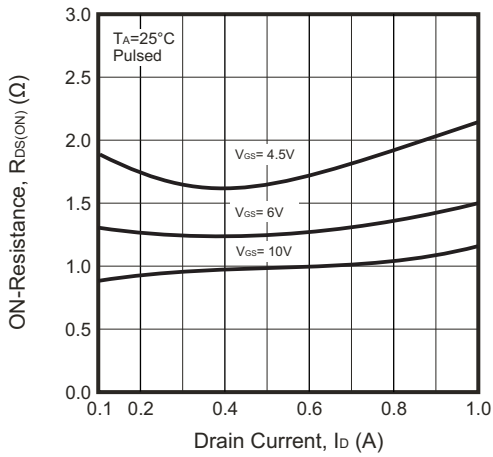


Fig.4 -  $R_{DS(ON)} - V_{GS}$

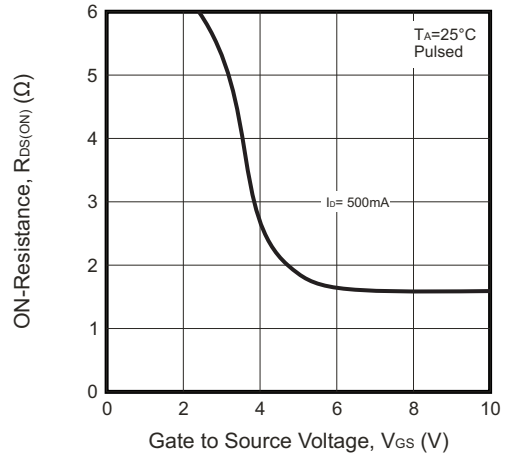
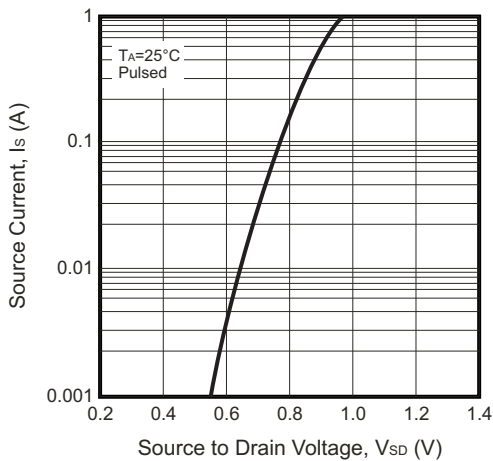
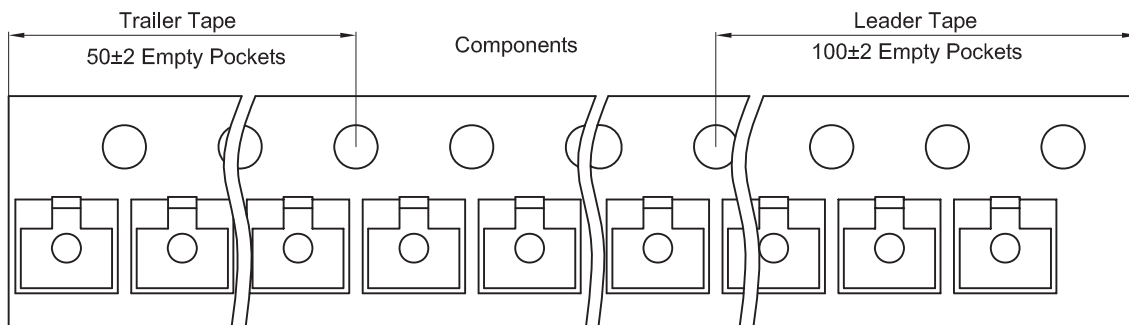
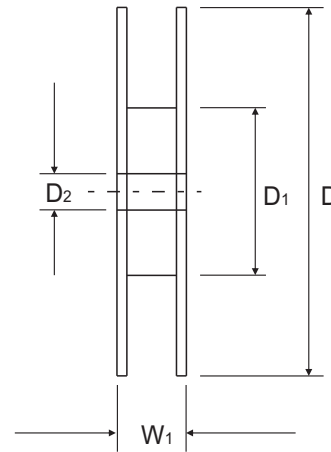
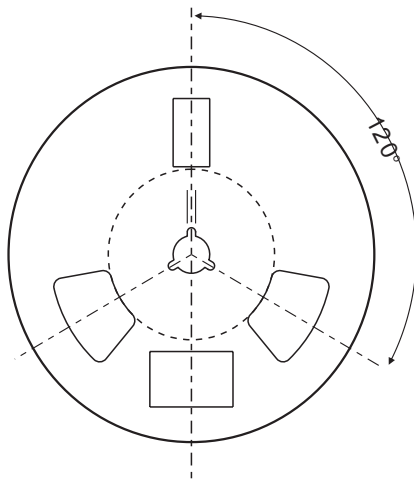
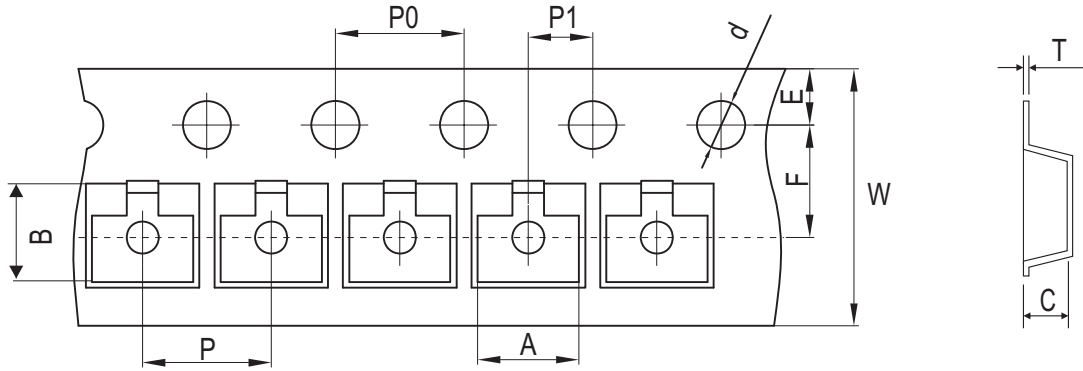


Fig.5 -  $I_S - V_{SD}$



### Reel Taping Specification

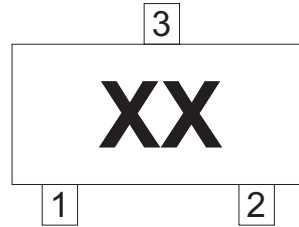


SOT-23	SYMBOL	A	B	C	d	D	D1	D2
	(mm)	3.15 ± 0.10	2.77 ± 0.10	1.22 ± 0.10	Φ1.50 ± 0.10	178 ± 2.00	54.40 ± 1.00	13.00 ± 1.00
	(inch)	0.124 ± 0.004	0.109 ± 0.004	0.048 ± 0.004	Φ0.059 ± 0.004	7.008 ± 0.079	2.142 ± 0.039	0.512 ± 0.039

SOT-23	SYMBOL	E	F	P	P0	P1	W	W1
	(mm)	1.75 ± 0.10	3.50 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.10	8.00 + 0.30 / - 0.10	12.30 ± 1.00
	(inch)	0.069 ± 0.004	0.138 ± 0.004	0.157 ± 0.004	0.157 ± 0.004	0.079 ± 0.004	0.315 + 0.012 / - 0.004	0.484 ± 0.039

## Marking Code

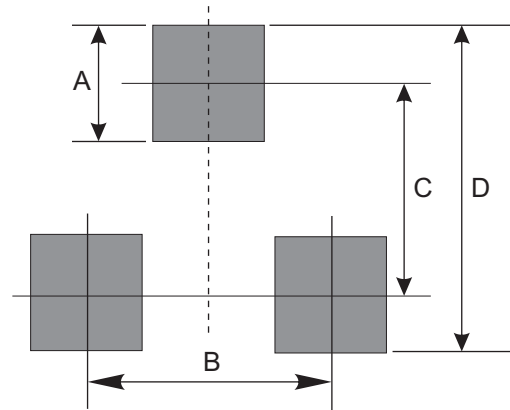
Part Number	Marking Code
BSS138-G	SS



xx = Product type marking code

## Suggested PAD Layout

SIZE	SOT-23	
	(mm)	(inch)
A	0.80	0.031
B	1.90	0.075
C	2.02	0.080
D	2.82	0.111



## Standard Packaging

Case Type	REEL PACK	
	REEL ( pcs )	Reel Size (inch)
SOT-23	3,000	7